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Paper code - U128-109CB(T1)

**MARCH 2019 / IN-SEM (T1)****F. Y. B.TECH. (Common/CB) (SEMESTER - II)****COURSE NAME: Engineering Physics (CB)****COURSE CODE: ES10184A-CB****(PATTERN 2018)**

Time: [1 Hour]

[Max. Marks: 20]

**(\*) Instructions to candidates:**

- 1) All questions are compulsory.
- 2) Figures to the right indicate full marks.
- 3) Use of scientific calculator is allowed.
- 4) Use suitable data where ever required.

Q1	Attempt any <b>two</b> .	
(a)	With the help of a neat diagram, derive the expression for fringe width for a thin wedge shaped film.	[4]
(b)	With the help of neat diagrams, derive the expression $E_\theta = E_m \left( \frac{\sin \alpha}{\alpha} \right)$ for Fraunhofer diffraction from a single slit.	[4]
(c)	Light from Mercury lamp is incident normally on a diffraction grating with 1200 lines/mm. Calculate the angles at which the spectral lines with wavelengths 576 and 579nm will occur in the first order. Hence find the dispersion in degrees per nm.	[4]
Q2	Attempt any <b>two</b> .	
(a)	Derive the expression for number of electrons per unit volume in the conduction band of a semiconductor.	[4]
(b)	Show that the Fermi energy lies at the centre of the band gap for an intrinsic semiconductor.	[4]
(c)	Calculate the probability of absence of an electron 0.1eV below the Fermi energy at T = 300K. Will this probability increase or decrease if the temperature is decreased by 100K?	[4]
Q3	Attempt any <b>one</b> .	
(a)	Prove that the maximum in the light spectrum emitted by a semiconductor with a band gap of $E_g$ at a temperature T occurs at an energy $E_g + \frac{kT}{2}$ .	[4]
(b)	Calculate the critical angle and $\frac{P_{\text{escape}}}{P_{\text{source}}}$ for light emitted by a semiconductor with refractive index 3.3 into a medium with refractive index 1.33.	[4]